# Anuj Goyal

Contact Assistant Professor

Materials Science & Metallurgical Engineering, +91 63988 33633
Indian Institute of Technology (IIT), Hyderabad anujgoyal@msme.iith.ac.in
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**Profile** I employ first-principles computational modeling and machine learning techniques to characterize and

predict properties of materials for electronics, computing, and energy applications

Research interests in computational materials discovery and design, metals and semiconductors (oxides, nitrides, chalcogenides, halides), electronic structure theory, defect physics and thermody-

namics, multi-scale modeling

Employment Assistant Professor Dec. 2022 – present

Materials Science & Metallurgical Engineering, Indian Institute of Technology, Hyderabad

Kandi - 502284, Sangareddy

Research Scientist II Nov. 2019 – Aug. 2022

Theory and Computation, Materials Physics Group,

National Renewable Energy Laboratory, Golden, CO 80401

Advisor: Dr. Stephan Lany, Sr. Scientist

Postdoctoral Fellow April 2016 – Oct. 2019

Department of Metallurgy and Materials Engineering, Colorado School of Mines, Golden, CO 80401

Advisor: Prof. Vladan Stevanović

Postdoctoral Associate Sept. 2015 – March 2016

Department of Materials Science and Engineering, University of Florida, Gainesville, FL 32611

Advisor: Prof. Simon R. Phillpot

Education Ph.D., Materials Science and Engineering, 2011 – 2015

University of Florida, Gainesville, FL 32611 GPA: 4.0/4.0

Dissertation: Multiscale computational modeling of defects in uranium dioxide

Advisor: Prof. Simon R. Phillpot

M.S., Materials Science and Engineering, 2010 – 2012

University of Florida GPA: 4.0/4.0

Gainesville, FL 32611

B.Tech. & M.Tech., Metallurgical and Materials Engineering, 2005 – 2010

Indian Institute of Technology, Madras GPA: 8.6/10.0

Chennai - 600036, India

#### Publications 2 under review, 18 published, and 4 in preparation

(Google Scholar: H-index = 13, Total citations  $\sim 855$ )

#### Manuscript under review:

- 1. M. Witman\*, A. Goyal\*, T. Ogitsu, A. H. McDaniel, and S. Lany, "Graph neural network modeling of vacancy formation enthalpy for materials discovery and its application in solar thermochemical water splitting", under review *Nature Computational Science* 2022. DOI:10.26434/chemrxiv-2022-frcns. (\*authors contributed equally.)
- 2. S. Roychoudhury, S. Shulda, **Anuj Goyal**, R. Bell, S. Sainio, N. Strange, J. E. Park, E. N. Coker, S. Lany, D. Ginley, David Prendergast, "Investigating the Electronic Structure of Prospective Watersplitting Oxide  $BaCe_{0.25}Mn_{0.75}O_{3-\delta}$  Before and After Thermal Reduction", under review *Chemistry of Materials* **2022**. ArXiv:2209.13267

#### **Published:**

- 3. N. A. Strange, J. Park, **A. Goyal**, R. T. Bell, J. Trindell, J. D. Sugar, K. Stone, E. N. Coker, S. Lany, S. Shulda, and D. S. Ginley, "Formation of 6H-Ba<sub>3</sub>Ce<sub>0.75</sub>Mn<sub>2.25</sub>O<sub>9</sub> during thermochemical reduction of 12R-Ba<sub>4</sub>CeMn<sub>3</sub>O<sub>12</sub>:Identification of a polytype in the Ba(Ce,Mn)O<sub>3</sub> family", *Inorganic Chemistry* 61, 16, 6128-6137 **2022**. DOI: 10.1021/acs.inorgchem.2c00282. Impact factor (IF) = 5.16
- 4. **A. Goyal**, A. Zakutayev, V. Stevanović and S. Lany, "Computational Fermi level engineering and doping-type conversion of Mg:Ga<sub>2</sub>O<sub>3</sub> via three-step synthesis processing", *Journal of Applied Physics* 129, 245704 **2021**. DOI: 10.1063/5.0051788. IF = 2.55
- 5. S. Sun, A. Tiihonen, F. Oviedo, Z. Liu, J. Thapa, N. T. P. Hartono, A. Goyal, C. Batali, A. Encinas, J. Yoo, R. Li, Z. Ren, M. Bawendi, V. Stevanović, J. Fisher and T. Buonassisi, "A physical data fusion approach to optimize compositional stability of halide perovskites", *Matter* 4, 1-18, April 7, 2021. DOI: 10.1016/j.matt.2021.01.008. IF = 15.59
- 6. **A. Goyal**, Y. Li, A. Chernatynskiy, J. S. Jayashankar, M. C. Kautzky, S. B. Sinnott and S. R. Phillpot, "The influence of alloying on the stacking fault energy of gold from density-functional theory calculations", *Computational Materials Science* 188, 110236 **2020**. DOI: 10.1016/j.commatsci.2020.110236. IF = 3.30
- 7. **A. Goyal**, P. Gorai, S. Anand, E. S. Toberer, G. J. Snyder and V. Stevanović, "On the dopability of semiconductors and governing material properties", *Chemistry of Materials* 32, 11, 4467-4480 **2020**. DOI: 10.1021/acs.chemmater.9b05126. IF = 9.81
- 8. P. Gorai, A. Goyal, E. S. Toberer and V. Stevanović, "A simple chemical guide for finding novel n-type dopable Zintl pnictide thermoelectric materials", Journal of Materials Chemistry A 7, 19385-19395 2019. DOI: 10.1039/C9TA03786A. IF = 12.73
- 9. **A. Goyal**, K. Mathew, R. G. Hennig, A. Chernatynskiy, C. R. Stanek, S. T. Murphy, D. A. Andersson, S. R. Phillpot and B. P. Uberuaga, "The conundrum of relaxation volumes in first-principles calculations of charge defects in UO<sub>2</sub>", *Applied Sciences* 9 (24), 5276 **2019**. DOI: 10.3990/app9245276. IF = 2.68
- 10. J. Male, M. T. Agne, **A. Goyal**, S. Anand, I. T. Witting, V. Stevanović and G. J. Snyder, "The importance of phase equilibrium for doping efficiency: iodine doped PbTe", *Materials Horizons* 6 (7), 1444-1453 **2019**. DOI: 10.1039/C9MH00294D.IF = 13.27

- 11. L. T. Schelhas, Z. Li, J. A, Christians, A. Goyal, P. Kairys, S. P. Harvey, D. H. Kim, K. H Stone, J. M. Luther, K. Zhu, V. Stevanović and J. J. Berry, "Insights into operational stability and processing of halide perovskite active layers", Energy & Environmental Science 12 (4), 1341-1348 2019. DOI: 10.1039/C8EE03051K. IF = 38.53
- 12. **A. Goyal**, and V. Stevanović, "Metastable rocksalt ZnO is *p*-type dopable", *Physical Review Materials* 2, 084603 **2018**. DOI:10.1103/PhysRevMaterials.2.084603. IF = 3.99
- 13. **A. Goyal**, S. McKechnie, D. Pashov, W. Tumas, M. van Schilfgaarde and V. Stevanović, "Origin of Pronounced Nonlinear Band Gap Behavior in Lead-Tin Hybrid Perovskite Alloys", *Chemistry of Materials* 30, 11, 3920-3928 **2018**. DOI:10.1021/acs.chemmater.8b01695. IF = 9.81
- 14. **A. Goyal**, P. Gorai, E. S. Toberer and V. Stevanović, "First-principles calculation of intrinsic defect chemistry and self-doping in PbTe", npj Computational Materials 3, 42 **2017**. DOI: 10.1038/s41524-017-0047-6. IF = 13.20
- 15. **A. Goyal**, P. Gorai, H. Peng, S. Lany, and V. Stevanović, "A computational framework for automation of point defect calculations", *Computational Materials Science* 130, 1-9 **2017**. DOI: 10.1016/j.commatsci.2016.12.040. **Editor's Choice**. IF = 3.30
- 16. S. A. Miller, P. Gorai, B. R. Ortiz, **A. Goyal**, D. Gao, S. A. Barnett, T. O. Mason, G. J. Snyder, Q. Lv, V. Stevanović and E. S. Toberer, "Capturing anharmonicity in a lattice thermal conductivity model for high-throughput predictions", *Chemistry of Materials* 29, 6, 2494-2501 **2017**. DOI: 10.1021/acs.chemmater.6b04179. IF = 9.81
- 17. Y. Li, A. Goyal, A. Chernatynskiy, J. S. Jayashankar, M. C. Kautzky, S. B. Sinnott and S. R. Phillpot, "Nanoindentation of gold and gold alloys by molecular dynamics simulations", *Materials Science and Engineering: A* 651, 346-357 **2016**. DOI: 10.1016/j.msea.2015.10.081. IF = 5.23
- 18. **A. Goyal**, S. R. Phillpot, G. Subramanian, D. A. Andersson, C. R. Stanek and B. P. Uberuaga, "Impact of homogeneous strain on uranium vacancy diffusion in uranium dioxide", *Physical Review B* 91, 094103 **2015**. DOI: 10.1103/PhysRevB.91.094103. IF = 4.04
- 19. K. Choudhary, T. Liang, A. Chernatynskiy, Z. Lu, **A. Goyal**, S. R. Phillpot and S. B. Sinnott, "Charge optimized many-body potential for aluminium", *Journal of Physics: Condensed Matter* 27, 015003 **2015**. DOI: 10.1088/0953-8984/27/1/015003. IF = 2.33
- 20. **A. Goyal**, T. Rudzik, B. Deng, M. Hong, A. Chernatynskiy, S. B. Sinnott and Simon R. Phillpot, "Segregation of ruthenium to edge dislocations in uranium dioxide", *Journal of Nuclear Materials* 441, 96-102 **2013**. DOI: 10.1016/j.jnucmat.2013.05.031. IF = 2.94

#### Manuscripts in preparation:

- 21. **A. Goyal**, M. Sanders, R. O' Hayre, and S. Lany, "Thermodynamic model for repulsive defect interactions in off-stoichiometric  $Sr_{1-x}Ce_xMnO_3$ ". In preparation.
- 22. **A. Goyal**, and S. Lany, "Electronic structure and thermodynamic defects modeling of Ba<sub>4</sub>XMn<sub>3</sub>O<sub>12</sub> (X=Nb,Ce,Pr) oxides for solar thermochemical hydrogen production". In preparation.
- 23. **A. Goyal**, A. Zakutayev, and V. Stevanović, "Rocksalt ZnO, a promising transparent, high-mobility, and ambipolar semiconductor", In preparation.

24. Ximeng Wang, **Anuj Goyal**, Peng Zhou, Juan C. Nino, Jonathan Scheffe, Stephan Lany, Simon R. Phillpot, "Doped LaMnO<sub>3</sub> for water splitting by density functional theory calculations", In preparation.

# Honors & Awards

Key Contributor Award, Materials Physics Group, MCCS Directorate, NREL, 2021
Research work highlighted at the Center for Next Generation of Materials Design, NREL, 2017
Best Poster Presentation Award, The Minerals, Metals and Materials Society (TMS), 2015
Outstanding International Graduate Student Award, University of Florida, 2014
Awarded Membership, Tau Beta Pi, Engineering Honor Society, 2014
Awarded Scholarship for MEV Summer School at Oak Ridge National Laboratory, 2012
Awarded Certificate of Outstanding Achievement, University of Florida, 2011-14 (won 4 times)
Awarded Graduate Aptitude in Engineering Scholarship at IIT Madras, India, 2009

#### **Invited Talks**

"Point Defects Modeling to Accelerate Materials Discovery in Solar Thermochemical Water Splitting", Indian Institute of Technology (IIT), Gandhinagar, Gujarat, India, September 20, 2022

"Point Defects Modeling to Accelerate Materials Discovery in Solar Thermochemical Water Splitting", Indian Institute of Technology (IIT), Hyderabad, Telangana, India, July 12, 2022

"Computational Approaches to Point Defects Modeling in Semiconductors", **Indian Institute of Science (IISc) Bangalore**, Karnataka, India, April 7, **2022** 

"Thermodynamic modeling of point defects", North American Solid State Chemistry Conference (NASSCC), Golden, CO, July 29, 2019

"Computationally guided design of materials", Los Alamos National Laboratory (LANL), Los Alamos, NM, April 16, 2018

"Multiscale computational modeling of defects in uranium dioxide", **National Renewable Energy Laboratory (NREL)**, Golden, CO, January 22, **2016** 

#### Conferences

#### Selected contributed talks:

**A. Goyal**, S. Bauers, and S. Lany, "Instability of rock-salt cubic NbN in density functional calculations", **APS March Meeting**, March 17 **2022** 

**A. Goyal**, M. Sanders, R. O'Hayre, and S. Lany, "Computational defect and thermodynamic modeling of redox behavior of complex oxides for solar thermochemical hydrogen (STCH) production", **MRS Fall Meeting**, Online, December 8 **2021** 

**A.** Goyal, A. Zakutayev, V. Stevanović and S. Lany, "Computational fermi level engineering and doping-type conversion of Ga<sub>2</sub>O<sub>3</sub> via three-step processing", **APS March Meeting**, Online, March 17 **2021** 

A. Goyal, A. Zakutayev, and V. Stevanović, "Ambipolar doping of rocksalt ZnO", 30<sup>th</sup> International Conference on Defects in Semiconductors, Seattle, WA, July 23, 2019

**A. Goyal**, Paul Kairys and V. Stevanović, "Understanding site-specific contributions to phase stability and band gap in hybrid perovskite", **European MRS Spring Meeting**, Nice, France, May 27, **2019** 

**A.** Goyal, Paul Kairys and V. Stevanović, "Understanding site-specific contributions to phase stability and band gap in hybrid perovskite", MRS Spring Meeting, Phoenix, AZ, April 4, 2018

- A. Goyal, P. Gorai, H. Peng, S. Lany and V. Stevanović, "A computational framework for automation of point defect calculations", APS March Meeting, New Orleans, LA, March 13, 2017
- **A. Goyal**, A. Chernatynskiy, G. Subramanian, D. A. Andersson, B. P. Uberuaga and S. R. Phillpot, "Sensitivity analysis and uncertainty quantification in a multi-scale model for defect diffusion under arbitrary strain fields", **MRS Spring Meeting**, Phoenix, AZ, March 31, **2016**
- **A.** Goyal, T. Rudzik, B. Deng, M. Hong, A. Chernatynskiy, S. B. Sinnott and Simon R. Phillpot, "Segregation of fission products to edge dislocations in uranium dioxide", **MRS Fall Meeting**, Boston, MA, December 3, **2013**

#### Selected poster presentations:

- A. Goyal, and V. Stevanović, "Metastable rocksalt ZnO is p-type dopable", Gordon Research Conference (GRC) on Defects in Semiconductors, New London, NH, August 19 24, 2018
- **A. Goyal**, G. Subramanian, D. A. Andersson, C. R. Stanek, S. R. Phillpot and B. P. Uberuaga, "Atomistic characterization of uranium vacancy interaction with external strains in UO<sub>2</sub>", **TMS Annual Meeting**, Orlando, FL, **2015**, (Won the best poster presentation award)

Skills

Electronic Structure Codes: VASP, Quantum-ESPRESSO, QUESTAAL

Molecular Dynamics Codes: LAMMPS, GULP

**Programming**: Python, FORTRAN, Mathematica, GNU Octave, Bash Computational Materials Tools: ATAT, Pylada, Pymatgen, ASE

GitHub Projects:

- Lead developer of Pylada-Defects a code for automating first principles point defect calculations
- Contributor to SPProC a physics informed machine learning tool for optimizing perovskite stability

## Academic Service

Reviewed articles for journals (ORCID: 0000-0001-5991-9562):

- npj Computational Materials
- Chemistry of Materials
- Journal of Physical Chemistry Letters
- Journal of Materials Science

- APL Materials
- Journal of Physical Chemistry C
- Computational Materials Science
- Journal of Applied Physics

#### References

# Dr. Stephan Lany

Senior Scientist,

National Renewable Energy Laboratory, Golden CO

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### Prof. Vladan Stevanović

Associate Professor,

Metallurgical and Materials Engineering,

Colorado School of Mines, Golden CO

E-mail: vstevano@mines.edu

#### Prof. Simon. R. Phillpot

Distinguished Professor,

Vladimir A. Grodsky Professor of Materials Science and Engineering,

Department of Materials Science and Engineering,

University of Florida, Gainesville, FL

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